RoHS

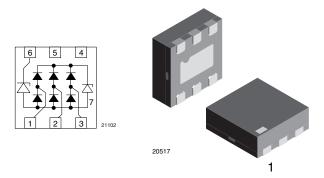
HALOGEN FREE

**GREEN** 



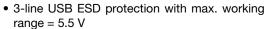
## Vishay Semiconductors

# **USB-OTG BUS-Port ESD Protection for V<sub>BUS</sub> = 28 V**



#### **FEATURES**

- Ultra compact LLP75-7L package
- Low package height < 0.6 mm



- V<sub>BUS</sub>-protection with 28 V working range
- · Low leakage current
- Low load capacitance C<sub>D</sub> = 0.7 pF
- ESD immunity to IEC 61000-4-2
   ± 15 kV contact discharge
   ± 15 kV air discharge
- Surge current acc. IEC 61000-4-5 I<sub>PP</sub> > 3 A
- e4 precious metal (e.g. Ag, Au, NiPd, NiPdAu) (no Sn)
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **MARKING** (example only)



Dot = pin 1 marking XX = date code YY = type code (see table below)

### **DESIGN SUPPORT TOOLS**

click logo to get started



ORDERING INFORMATION						
DEVICE NAME ORDERING CODE		TAPED UNITS PER REEL (8 mm TAPE on 7" REEL)	MINIMUM ORDER QUANTITY			
VBUS053CZ-HAF	VBUS053CZ-HAF-G-08	3000	15 000			

PACKAGE DATA							
DEVICE NAME	PACKAGE NAME	TYPE CODE	WEIGHT	WEIGHT MOLDING COMPOUND MOISTURE SENSITIVITY LEVEL		SOLDERING CONDITIONS	
VBUS053CZ-HAF	LLP75-7L	UA	4.2 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	Peak temperature max. 260 °C	

ABSOLUTE MAXIMUM RATINGS VBUS053CZ-HAF							
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT			
Data line D+, D-, ID: Pin 1, 2 and 3 to ground (pin 7)							
Peak pulse current	acc. IEC 61000-4-5; t <sub>P</sub> = 8/20 μs; single shot	I <sub>PPM</sub>	3	Α			
Peak pulse power	acc. IEC 61000-4-5; t <sub>P</sub> = 8/20 μs; single shot	P <sub>PP</sub>	54	W			
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V	± 15	kV			
	Air discharge acc. IEC 61000-4-2; 10 pulses	$V_{ESD}$	± 15	kV			
V <sub>BUS</sub> : Pin 6 to ground (pin 7)							
Peak pulse current	acc. IEC 61000-4-5; t <sub>P</sub> = 8/20 μs; single shot	I <sub>PPM</sub>	3	А			
Peak pulse power	acc. IEC 61000-4-5; t <sub>P</sub> = 8/20 μs; single shot	P <sub>PP</sub>	156	W			
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V	± 30	kV			
	Air discharge acc. IEC 61000-4-2; 10 pulses	$V_{ESD}$	± 30	kV			
Operating temperature	Junction temperature	TJ	-40 to +125	°C			
Storage temperature		T <sub>STG</sub>	-55 to +150	°C			

Rev. 1.7, 08-Jan-2019

1 Document Number: 85200
For technical questions, contact: ESDprotection@vishav.com



PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of line which can be protected	N <sub>channel</sub>	-	-	3	lines
Reverse working voltage	Reverse stand-off voltage	$V_{RWM}$	-	-	5.5	V
Reverse voltage	at I <sub>R</sub> = 0.1 μA	$V_{R}$	5.5	-	-	V
Reverse current	at V <sub>R</sub> = 3.3 V	I <sub>R</sub>	-	-	0.02	μΑ
	at V <sub>R</sub> = 3.3 V; T = 65 °C	I <sub>R</sub>	-	-	0.085	μΑ
	at V <sub>R</sub> = V <sub>RWM</sub> = 5.5 V	I <sub>R</sub>	-	-	0.1	μΑ
Forward voltage	at I <sub>F</sub> = 15 mA	V <sub>F</sub>	0.7	-	1.2	V
Reverse breakdown voltage	at I <sub>R</sub> = 1 mA	$V_{BR}$	6.5	-	10	V
Reverse clamping voltage	at I <sub>PP</sub> = 1 A; acc. IEC 61000-4-5	$V_{C}$	-	10	12	V
	at I <sub>PP</sub> = 3 A; acc. IEC 61000-4-5	V <sub>C</sub>	-	15	18	V
Forward clamping voltage	at I <sub>F</sub> = 3 A; acc. IEC 61000-4-5	$V_{F}$	-	3.4	4.1	V
Line capacitance	Test pin at $V_R = 0 \text{ V}$ ; any other I/O pin at $V_R = 3.3 \text{ V}$ ; $f = 1 \text{ MHz}$	C <sub>D</sub>	-	0.7	1	pF
Line to line capacitance	Among pins 1, 2 and 3 at V <sub>R</sub> = 0 V; f = 1 MHz	C <sub>D</sub>	-	0.35	0.5	pF
Line symmetry	Difference of the line capacitance	dC <sub>D</sub>	-	-	0.1	pF

#### Note

· Ratings at 25 °C ambient temperature, unless otherwise specified

ELECTRICAL CHARACTERISTICS V <sub>BUS</sub> (pin 6) to ground (pin 7)							
PARAMETER	TEST CONDITIONS/REMARKS SYM		MIN.	TYP.	MAX.	UNIT	
Protection paths	Number of line which can be protected	N <sub>channel</sub>	-	-	1	lines	
Reverse working voltage	Reverse stand-off voltage	$V_{RWM}$	-	-	28	V	
Reverse voltage	at I <sub>R</sub> = 0.1 μA	$V_R$	28	-	-	V	
Reverse current	at V <sub>R</sub> = V <sub>RWM</sub> = 28 V	I <sub>R</sub>	-	-	100	nA	
Forward voltage	at I <sub>F</sub> = 10 mA	V <sub>F</sub>	0.6	0.75	0.9	V	
Reverse breakdown voltage	at I <sub>R</sub> = 1 mA	$V_{BR}$	32	-	40	V	
Reverse clamping voltage	at I <sub>PP</sub> = 1 A; acc. IEC 61000-4-5; T = 25 °C	V <sub>C</sub>	-	37	45	V	
	at I <sub>PP</sub> = 3 A; acc. IEC 61000-4-5; T = 25 °C	V <sub>C</sub>	-	42	52	V	
Forward clamping voltage	at I <sub>F</sub> = 3 A; acc. IEC 61000-4-5	$V_{F}$	-	-	2.2	V	
Line capacitance	at V <sub>R</sub> = 0 V; f = 1 MHz	C <sub>D</sub>	-	31	40	pF	

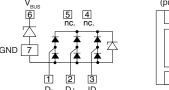
#### Note

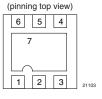
### **APPLICATION NOTE**

The VBUS053CZ-HAF is intended as an ESD protection and transient voltage suppressor for one USB-OTG port.

The LLP75-7L package contains two separate dies which are mounted on a common ground plane (pin 7).

The high-speed data lines D-, D+ and ID, are connected to any of the pins no. 1 to 3. As long as the signal voltage on the data lines is between the ground- and the 5 V working range, the low capacitance PN-diodes offer a very high isolation to ground and to the other data lines. But as soon as any transient signal like an ESD signal, exceeds this working range of 5 V in either the positive or negative direction, one of the PN-diodes gets into the forward mode and clamps the transient either to ground or to the avalanche break through level. An extra avalanche diode (separate die) clamps the supply line voltage (V<sub>BUS</sub> at pin 6) above the 28 V working range to ground (pin 7). Due to the "two die construction" the V<sub>BUS</sub> line has a very high isolation to the data lines. In case of a destructive transient signal, i.e. coming from a charger, the data lines will not be influenced.





#### Remark:

The input pins no. 1, 2 and 3 are symmetrical. Each of the data signals D-, D+ and ID can be connected to pin 1, 2 or 3

<sup>•</sup> Ratings at 25 °C ambient temperature, unless otherwise specified

### **TYPICAL CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

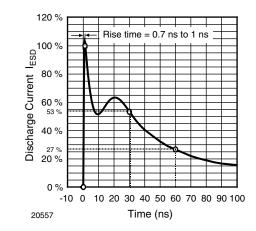


Fig. 1 - ESD Discharge Current Wave Form acc. IEC 61000-4-2 (330  $\Omega/150$  pF)

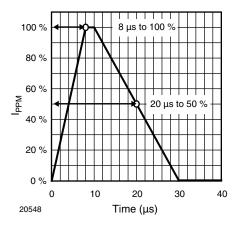


Fig. 2 - 8/20 µs Peak Pulse Current Wave Form acc. IEC 61000-4-5

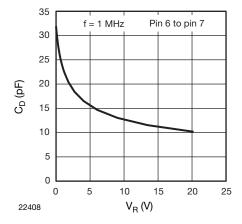


Fig. 3 - Typical Capacitance C<sub>D</sub> vs. Reverse Voltage V<sub>R</sub>

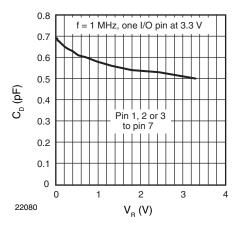


Fig. 4 - Typical Capacitance  $C_{\text{D}}$  vs. Reverse Voltage  $V_{\text{R}}$ 

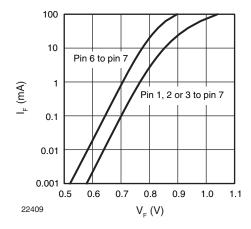


Fig. 5 - Typical Forward Current  $I_{\text{F}}$  vs. Forward Voltage  $V_{\text{F}}$ 

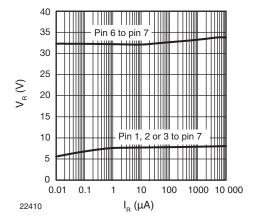


Fig. 6 - Typical Reverse Voltage  $V_{\mbox{\scriptsize R}}$  vs.Reverse Current  $I_{\mbox{\scriptsize R}}$ 

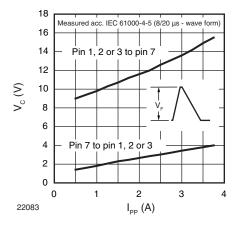


Fig. 7 - Typical Peak Clamping Voltage  $V_{C}$  vs. Peak Pulse Current  $I_{PP}$ 

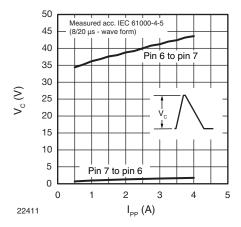


Fig. 8 - Typical Peak Clamping Voltage V<sub>C</sub> vs. Peak Pulse Current I<sub>PP</sub>

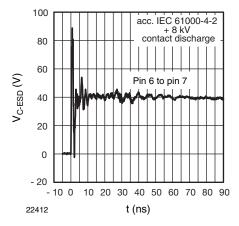


Fig. 9 - Typical Clamping Performance at + 8 kV Contact Discharge (acc. IEC 61000-4-2)

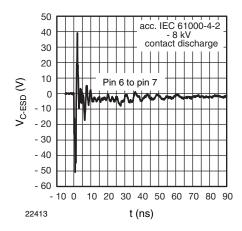


Fig. 10 - Typical Clamping Performance at - 8 kV Contact Discharge (acc. IEC 61000-4-2)

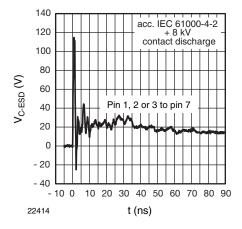


Fig. 11 - Typical Clamping Performance at + 8 kV Contact Discharge (acc. IEC 61000-4-2)

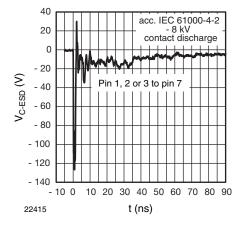


Fig. 12 - Typical Clamping Performance at - 8 kV Contact Discharge (acc. IEC 61000-4-2)

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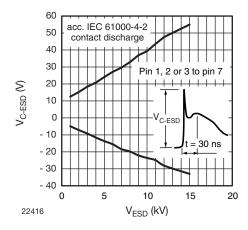


Fig. 13 - Typical Clamping Voltage at after 30 ns of ESD Contact Discharge (acc. IEC 61000-4-2)

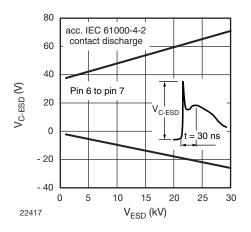
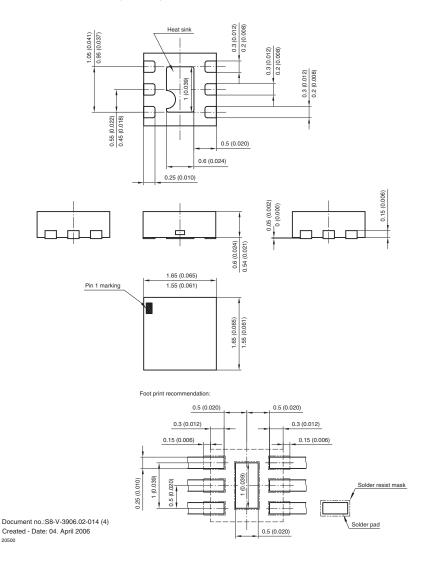
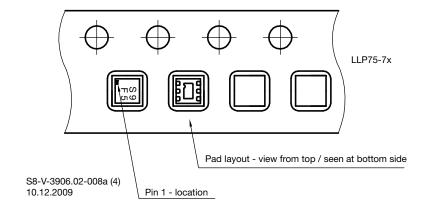


Fig. 14 - Typical Clamping Voltage at after 30 ns of ESD Contact Discharge (acc. IEC 61000-4-2)

### PACKAGE DIMENSIONS in millimeters (inches): LLP75-7L







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